ABSTRACT OF THE DISCLOSURE

present disclosure relates to an organic antireflective coating composition and a method for forming photoresist patterns using the same. The anti-reflective coating compositions are useful for preventing reflection of a lower film layer or a substrate of a photoresist film, reducing standing waves caused by light and variations in the thickness of the photoresist itself, and increasing the uniformity of the photoresist patterns. More particularly, the present invention relates to an organic anti-reflective coating composition comprising particular organo-silicon based polymers and a method for forming photoresist patterns using the The organic anti-reflective coating same. composition can prevent excessive absorbency of an antireflective film formed therefrom and, thus, minimize the reflectivity of the film so that it can efficiently remove and standing waves increase the uniformity of the photoresist pattern.